PRODUCT DESCRIPTION

The AD8541RMZ-REEL (single), AD8542ARMZ-REEL (dual) and AD8544ARMZ-REEL (quad) are low voltage micro power CMOS voltage feedback operational amplifiers. With an excellent bandwidth of 1.

3MHz, aslew rate of 0.9V/μs, and a quiescent current of 70μA per amplifier at 5V, the AD854xARMZ-REEL family can be designed into a wide range of applications. The AD854xARMZ-REEL op-amps are specifically designed for general-purpose applications with optimal performance. They have a wide input common-mode voltage range and excellent output voltage swings, and the maximum input offset voltage are 2.5mV. These parts provide rail-to-rail output swing into heavy loads. The AD854xARMZ-REEL family is specified for single or dual power supplies of +2.2V to +5.5V. The AD8541ARMZ-REEL is available in 5-lead SC-70 and SOT-23, and 8-lead SOP packages.

The AD8542ARMZ-REEL is available in 8-lead MSOP and SOP packages. The AD8544ARMZ-REEL is available in 14-lead SOP packages.

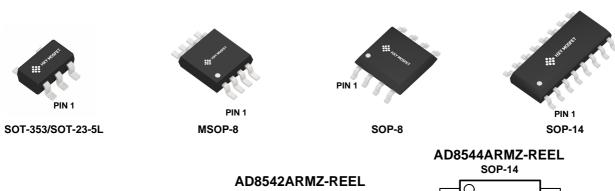
FEATURES

- Low Offset Voltage: 3.0 mV Maximum
- Gain-Bandwidth Product: 1.2MHz
- High Slew Rate: 1.0 V/µs
- Low Power: 85 µA per Amplifier Supply Current
- Unity Gain Stable
- Rail-to-Rail Input and Output
- Input Voltage Range: -0.2 to +5.2 V at 5V Supply
- Operating Power Supply: +2.2 to +5.5 V
- Operating Temperature Range: -40 °C to +125 °C
- ESD Rating: HBM 4kV, CDM 2kV

APPLICATIONS

- Smoke/Gas/Environment Sensors
- Audio Outputs
- Active Filters
- ASIC Input or Output Amplifier
- Sensor Interfaces
- Portable Equipment
- Battery-Powered Instrumentation

PIN CONFIGURATION



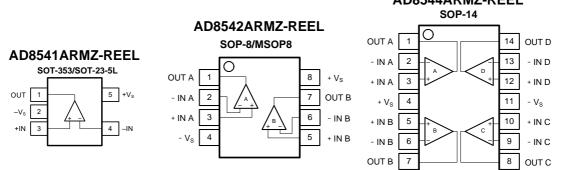


Figure 1. Pin Assignment Diagram

1MHz General Purpose, RRIO CMOS Amplifers

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, +V _S to -V _S	7V
Input Common Mode Voltage Range	
(-V _S) -	-0.5V to (+V _S) + 0.5V
Storage Temperature Range	65°C to +150°C
Junction Temperature	+160°C
Lead Temperature (Soldering 10sec)	+260°C
ESD Susceptibility	
НВМ	4000V
MM	400V
CDM	2000V

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range-40°C to +125°C

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device.

This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied.

Exposure to absolute maximum rating conditions for extended periods may affect reliability.

OEDEROMG OMFORMATION

Type Number	Package Name	Package Quantity
AD8541ARTZ-REEL	SOT-23-5L	3000
AD8541AKSZ-REEL	SC-70-5L	3000
AD8542ARZ-REEL	SOP-8L	2500
AD8542ARMZ-REEL	MSOP-8L	3000
AD8544ARZ-REEL	SOP-14L	2500

ELECRRICAL CHARACTERISTICS

Vs = 5.0V, $T_A = +25^{\circ}C$, $V_{CM} = Vs / 2$, $V_O = Vs / 2$, and $R_L = 10k\Omega$ connected to Vs / 2, unless other wise noted. Boldface limits apply over the specified temperature range, $T_A = -40$ to $+ 125^{\circ}C$.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Vos	Input offset voltage			±1.0	±3.0	mV
VosTc	Offset voltage drift	T _A = - 40 to +125 °C		±1	3.5	μV/°C
PSRR	Power supply	Vs= 2.2 to 5.5 V, VcM< Vs+-2V	80	110		- dB
1 OKK	rejection ratio	T _A = - 40 to +125 °C	75			ub ub
IB Input bias current			5	50		
	Input bias current	T _A = +85 °C			200	pА
	T _A = +125 °C			2000		
los	Input offset current			10	50	pА
Vn	Input voltage noise	f = 0.1 to 10 Hz		6		μV _{P-P}
	Input voltage noise	f = 10 kHz		27		nV/√Hz
	density	f = 1 kHz		30		110/0 円2
In	Input current noise density	f = 1 kHz		5		fA/√Hz

1MHz General Purpose, RRIO CMOS Amplifers

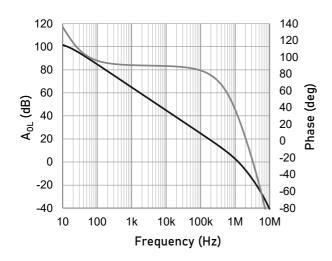
ELECRRICAL CHARACTERISTICS

 $Vs = 5.0V, T_A = +25 ^{\circ}C, \ V_{CM} = Vs \ / \ 2, \ Vo = Vs \ / \ 2, \ and \ R_L = 10 k\Omega \ connected \ to \ Vs \ / \ 2, \ unless \ other \ wise \ noted.$ Boldface limits apply over the specified temperature range, $T_A = -40 \ to \ + \ 125 ^{\circ}C.$

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
Vсм	Common-mode voltage range		Vs0.1		Vs++0.1	V	
		Vs= 5.5 V,Vcм= − 0.1 to 5.6 V	70	83			
	Common-mode	V _{CM} = 0 to 5.3 V, T _A = -40 to +125 °C	65				
CMRR	rejection ratio	Vs= 2.2 V,VcM= - 0.1 to 2.2 V	65	77		– dB	
		Vcm= 0 to 2.2 V,Ta= -40 to +125 °C	60				
C···	Innut conscitores	Differential		2.0			
Cin Input c	Input capacitance	Common mode		3.5		pF	
		$R_L = 25 \text{ k}\Omega$, $V_0 = 0.05 \text{ to } 3.5 \text{ V}$	90	105			
Δ	Open-loop voltage	T _A = -40 to +125 °C	85			٩D	
Avol	gain	$R_L = 2 k\Omega$, $V_O = 0.15 \text{ to } 3.5 \text{ V}$	85	100		dB	
	T _A = -40 to +125 °C	80					
GBW	Gainbandwidth product			1.2		MHz	
SR	Slew rate	G = +1, CL= 100 pF, Vo= 1.5 to 3.5	V	1.0		V/µs	
THD+N	Total harmonic distortion + noise	G = +1, f = 1 kHz, Vo = 1 V _{RMS}		0.003		%	
4-		To 0.1%, G = +1, 1V step		1.5			
ts	Settling time	To 0.01%, G = +1, 1V step		1.8		μs	
tor	Overload recovery time	To 0.1%, V _{IN} * Gain > Vs		2.5		μs	
Vон	High output voltage	RL= 50 kΩ	Vs+-6	Vs+ - 3		mV	
VOH	swing	R _L = 2 kΩ	Vs+-100	Vs+-65		IIIV	
Vol	Low output voltage	RL= 50 kΩ		Vs-+2	Vs-+4	mV	
/OL	swing	$RL= 2 k\Omega$		Vs-+43	Vs-+65	1111	
lsc	Short-circuit current	Source current through 10Ω		40		mΛ	
130	Short-circuit current	Sink current through 10Ω		50		- mA	
Vs	Operating supply voltage		2.2		5.5	V	
lo.	Quiescent current			85	120	^	
	(per amplifier)	T _A = −40 to +125 °C			150	μΑ	
Та	Operating temperature range		-40		+125	°C	

TYPICAL PERFORMANCE CHARACTERISTICS

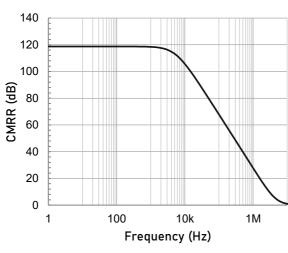
At T_A = +25°C, V_{CM} = $V_S/2$, and R_L = 10k Ω connected to $V_S/2$, unless otherwise noted.

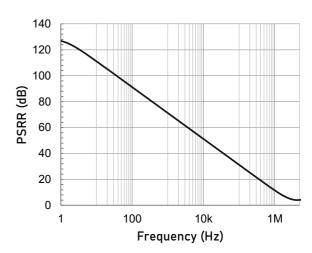


1,000 (THZ) 100 (Noise Noise N

Open-loop Gain and Phase as a function of Frequency.

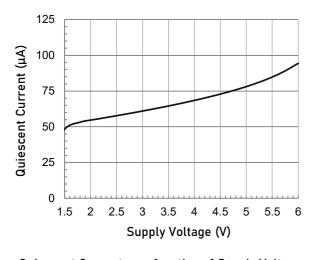
Input Voltage Noise Spectral Density as a function of Frequency.

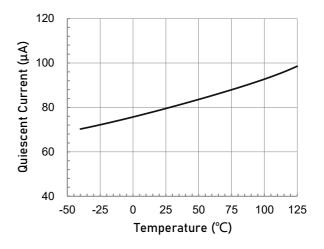




Common-mode Rejection Ratio as a function of Frequency.

Power Supply Rejection Ratio as a function of Frequency.



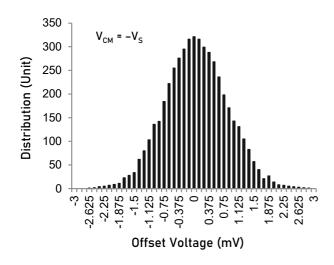


Quiescent Current as a function of Supply Voltage.

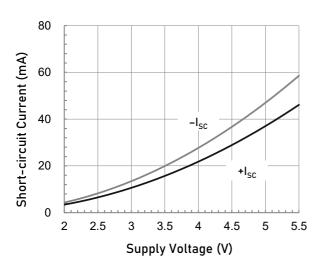
Quiescent Current as a function of Temperature.

TYPICAL PERFORMANCE CHARACTERISTICS

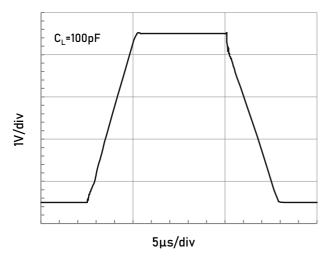
At T_A = +25°C, V_{CM} = $V_S/2$, and R_L = 10k Ω connected to $V_S/2$, unless otherwise noted.



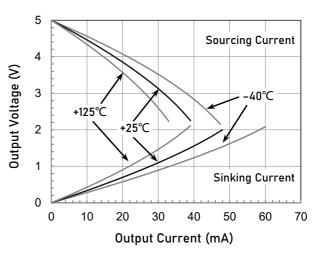
Offset Voltage Production Distribution



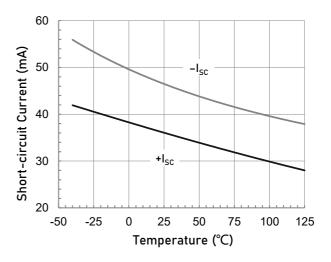
Short-circuit Current as a function of Supply Voltage.



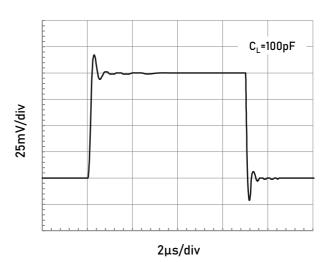
Large Signal Step Response.



Output Voltage Swing as a function of Output Current.



Short-circuit Current as a function of Temperature.



Small Signal Step Response.

1MHz General Purpose, RRIO CMOS Amplifers

APPLICATION NOTE

Size

AD854X family series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the AD854X family packages save space on printed circuit boards and enable the design

of smaller electronic products.

Power Supply Bypassing and Board Layout

AD854X family series operates from a single 2.2V to 5.5V supply or dual $\pm 1.0V$ to $\pm 3V$ supplies.For best performance, a $0.1\mu F$ ceramic capacitor should be placed close to the V_{DD} pin in single supply operation. For dual supply operation, both V_{DD} and V_{SS} supplies should be bypassed to ground with separate $0.1\mu F$ ceramic capacitors.

Low Supply Current

The low supply current (typical 85µA per channel) of AD854X family will help to maximize battery life. They are ideal for battery powered systems.

Operating Voltage

AD854X family operates under wide input supply voltage (2.2V to 5.5V). In addition, all temperature specification apply from -40°C to +125°C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime.

Rail-to-Rail Input

The input common-mode range of AD854X family extends 100mV beyond the supply rails (V_{SS} -0.1V to V_{DD} +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of AD854X family can typically swing to less than 10mV from supply rail in light resistive loads (>100k Ω), and 60mV of supply rail in moderate resistive loads (10k Ω).

Capacitive Load Tolerance

The AD854X family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2 shows a unity gain follower using the series resistor strategy. The resistor is olates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

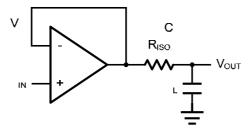


Figure 2 Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. However, if there is a resistive load R_L in parallel with the capacitive load, a voltage divider (proportional to R_{ISO}/R_L) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R_F provides the DC accuracy by feed-forward the V_{IN} to R_L . C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C_F . This in turn will slow down the pulse response.

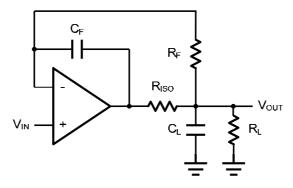


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy

INSTRUMENTATION AMPLIFIER

The triple AD854x family can be used to build a three-op-amp instrumentation amplifier as shown in Figure 4. The amplifier in Figure 4 is a high input impedance differential amplifier with gain of R_2/R_1 . The two differential voltage followers assure the high input impedance of the amplifier.

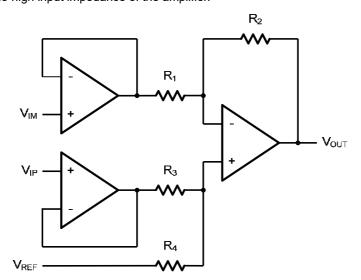


Figure 4. Instrument Amplifier

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TYYPICAL APPLICATION CIRCUITS

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs.

It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 5.shown the differential amplifier using AD854xARMZ-REEL family.

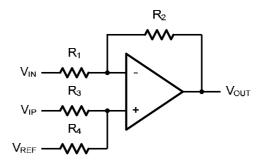


Figure 5. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{\text{IN}}^2 - V_{\text{IR}}^R + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e. $R_1=R_3$ and $R_2=R_4$), then

$$V_{\text{OUT}} = \frac{R_2}{R_1} (V_{\text{IP}} - V_{\text{IN}}) + V_{\text{REF}}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 6. The DC gain is defined by $-R_2/R_1$. The filter has a -20dB/decade roll-off after its corner frequency $f_C=1/(2\pi R_3C_1)$.

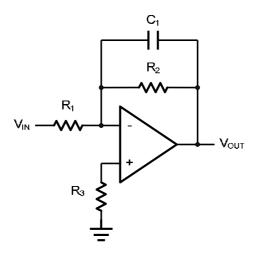
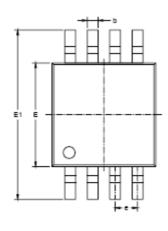


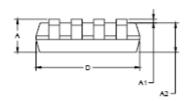
Figure 6. Low Pass Active Filter



PACKAGE OUTLINE DIMENSIONS MSOP-8

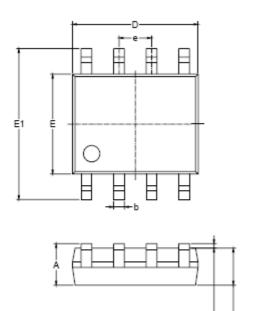


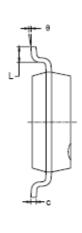




Symbol	Dimer In Milli	nsions meters	Dimensions In Inches		
-	MIN	MAX	MIN	MAX	
Α	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.250	0.380	0.010	0.015	
С	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
E	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
e	0.650 BSC		0.026	BSC	
L	0.400	0.800	0.016	0.031	
θ	0°	6°	0°	6°	

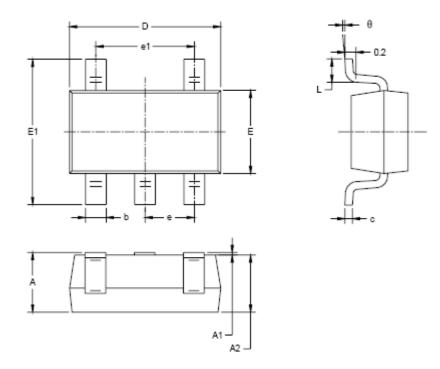
SOP-8





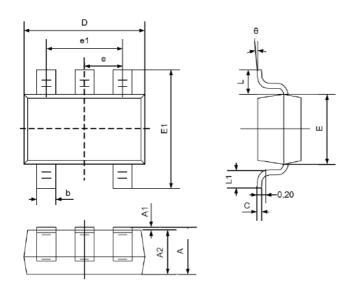
Symbol	Dimensions In Millimeters		Dimensions In Inches		
	MIN	MAX	MIN	MAX	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
e	1.27 BSC		0.050	BSC	
L	0.400	1.270	0.016	0.050	
9	0°	8°	0°	8°	

SOT-23-5L



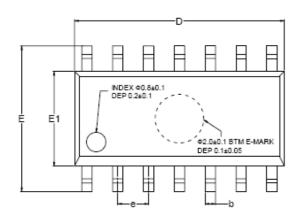
Symbol	Dimensions In Millimeters		Dimensions In Inches		
-,	MIN	MAX	MIN	MAX	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950	0.950 BSC		BSC	
e1	1.900 BSC		0.075	BSC	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

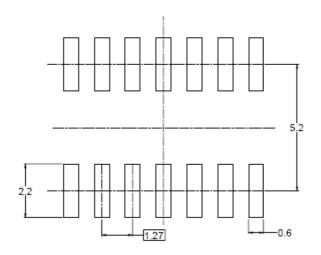
SC-70-5L



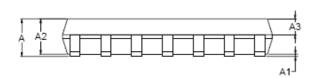
	Dimens	sions	Dimensions		
Symbol	In Milli	meters	In Inches		
	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080 0.150		0.003	0.006	
D	2.000	2.000 2.200		0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650T	ΥP	0.026T	ΥP	
e1	1.200	1.400	0.047	0.055	
L	0.525REF		0.021REF		
L1	0.260	0.460	0.010	0.018	
θ	0°)° 8°		8°	

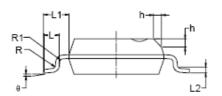
SOP-14





RECOMMENDED LAND PATTERN (Unit: mm)





S.mah al	Dimensions In Millimeters		Dimensions In Inches		ches	
Symbol	MIN	MOD	MAX	MIN	MOD	MAX
Α	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.25		1.65	0.049		0.065
A3	0.55		0.75	0.022		0.030
b	0.36		0.49	0.014		0.019
D	8.53		8.73	0.336		0.344
E	5.80		6.20	0.228		0.244
E1	3.80		4.00	0.150		0.157
е		1.27 BSC		0.050 BSC		
L	0.45		0.80	0.018		0.032
L1		1.04 REF		0.040 REF		
L2		0.25 BSC		0.01 BSC		
R	0.07			0.003		
R1	0.07			0.003		
h	0.30		0.50	0.012		0.020
θ	0°		8°	0°		8°

1MHz General Purpose, RRIO CMOS Amplifers

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